

IPA65R225C7XKSA1

IPA65R225C7XKSA1 Information

11 = 11	ww.heisoms.com	 IPA65R225C7XKSA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 650V TO220-3 TO-220-3 Full Pack For the pricing/inventory/lead time, please contact us	
Fo	or Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPA65R225C7XKSA1 Specifications

Manufacturer Part Number	IPA65R225C7XKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack
Series	CoolMOS? C7
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	7A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 240µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	996pF @ 400V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	29W (Tc)
Rds On (Max) @ Id, Vgs	225 mOhm @ 4.8A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO220-FP
Package / Case	TO-220-3 Full Pack
	Report errors?

IPA65R225C7XKSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPA65R225C7XKSA1 Payment Methods



If you have any question about IPA65R225C7XKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com